

ECELCDE5VU

Ultra Low Capacitance Array for ESD Protection

The ECELCDE5VU provides a typical line to line capacitance of 0.35pF and low insertion loss up to 3GHz providing greater signal integrity making it ideally suited for USB 2.0 applications, such as Digital TVs, DVD players, Computing, set-top boxes and MDDI applications in mobile computing devices.

It has been specifically designed to protect sensitive components which are connected to high-speed data and transmission lines from overvoltage caused by ESD(electrostatic discharge), CDE (Cable Discharge Events),and EFT (electrical fast transients).

Features

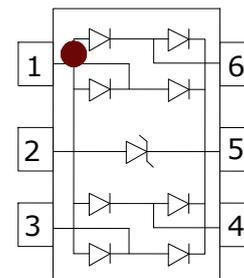
- Protects four I/O lines and one Vcc line
- Low capacitance
- Working voltages : 5V
- Low leakage current
- Low capacitance (<0.7pF) for high-speed interfaces
- No insertion loss to 3.0GHz
- Response Time is < 1 ns
- Meets MSL 1 Requirements
- Solid-state silicon avalanche technology
- ROHS compliant



SOT23-6L

Main applications

- Digital Visual Interface (DVI)
- 10/100/1000 Ethernet
- USB 1.1/2.0/3.0/3.1/OTG
- IEEE 1394 Firewire Ports
- Projection TV Monitors and Flat Panel Displays
- Notebook Computers
- Set Top Box
- Projection TV



Protection solution to meet

- IEC61000-4-2 (ESD) ±15kV (air), ±15kV (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)

Ordering Information

Device	Qty per Reel	Reel Size
ECELCDE5VU	3000	7 Inch

Maximum ratings (Temp=25°C Unless Otherwise Specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (tp=8/20µs waveform)	P _{PPP}	150	Watts
ESD Rating per IEC61000-4-2:	Contact	15	KV
	Air	15	
Lead Soldering Temperature	T _L	260 (10 sec.)	°C
Operating Temperature Range	T _J	-55 ~ 150	°C
Storage Temperature Range	T _{STG}	-55 ~ 150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

*Other voltages may be available upon request.

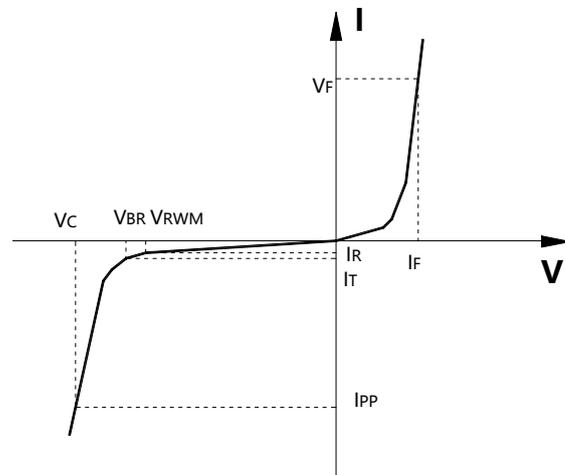
1. Non-repetitive current pulse, per Figure 1.

Electrical characteristics (Temp=25°C Unless Otherwise Specified)

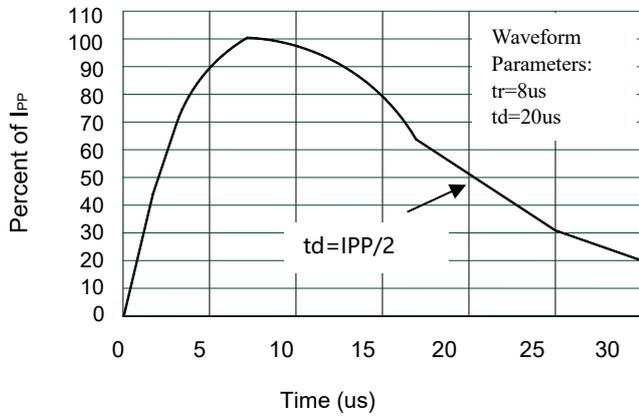
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V _{RWM}	Reverse Working Voltage	Any I/O to Ground			5.0	V
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA, Any I/O to Ground	6.0			V
I _R	Reverse Leakage Current	V _{RWM} = 5V, Any I/O to Ground			1	µA
V _F	Diode Forward Voltage	I _F = 15mA		0.85	1.2	V
V _C	Clamping Voltage	I _{PP} = 1A, tp = 8/20µs, any I/O pin to Ground			15.5	V
		I _{PP} = 5A, tp = 8/20µs, any I/O pin to Ground			25	V
C _J	Junction Capacitance	V _R = 0V, f = 1MHz, between I/O pins		0.35	0.45	pF
		V _R = 0V, f = 1MHz, any I/O pin to Ground		0.65	0.7	pF

Junction capacitance is measured in V_R=0V, F=1MHz

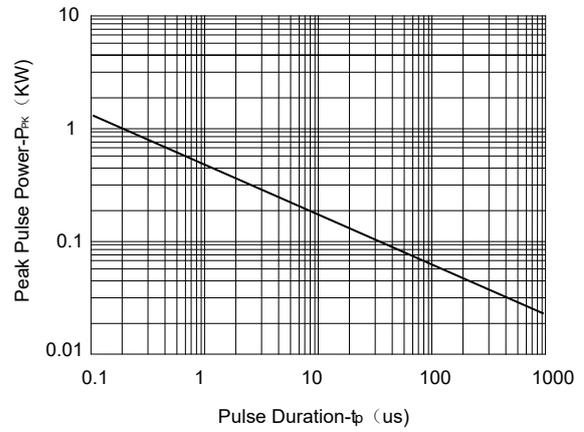
Symbol	Parameter
V _{RWM}	Working Peak Reverse Voltage
V _{BR}	Breakdown Voltage @ I _T
V _C	Clamping Voltage @ I _{PP}
I _T	Test Current
I _{RM}	Leakage current at V _{RWM}
I _{PP}	Peak pulse current
C _O	Off-state Capacitance
C _J	Junction Capacitance



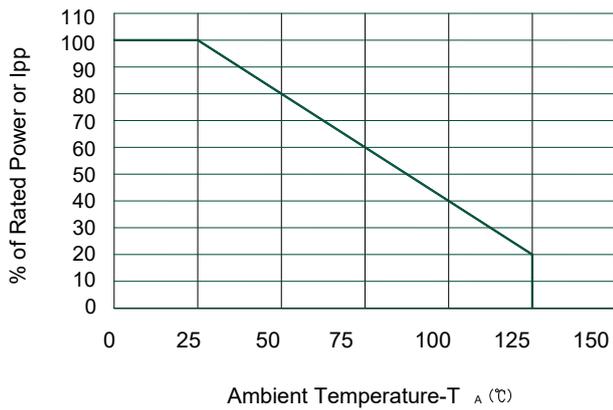
Typical electrical characterist applications



Pulse Waveform



Non-Repetitive Peak Pulse Power vs. Pulse Time



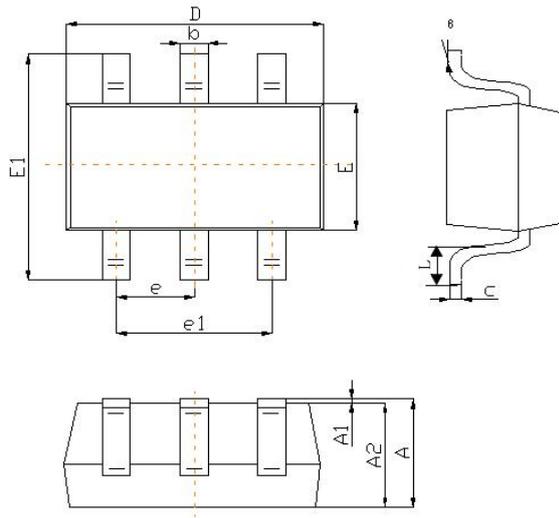
Power Derating Curve

Package Information

SOT23-6L

Mechanical Data

- Case: SOT23-6L
- Case Material: Molded Plastic. UL Flammability



DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
theta	0	8°	0	8°

Recommended Pad outline

